

Magnetic Properties of MBE Grown $\text{La}_{1/3}\text{Y}_{1/3}\text{Sr}_{1/3}\text{MnO}_3$ Thin Films and Superlattices

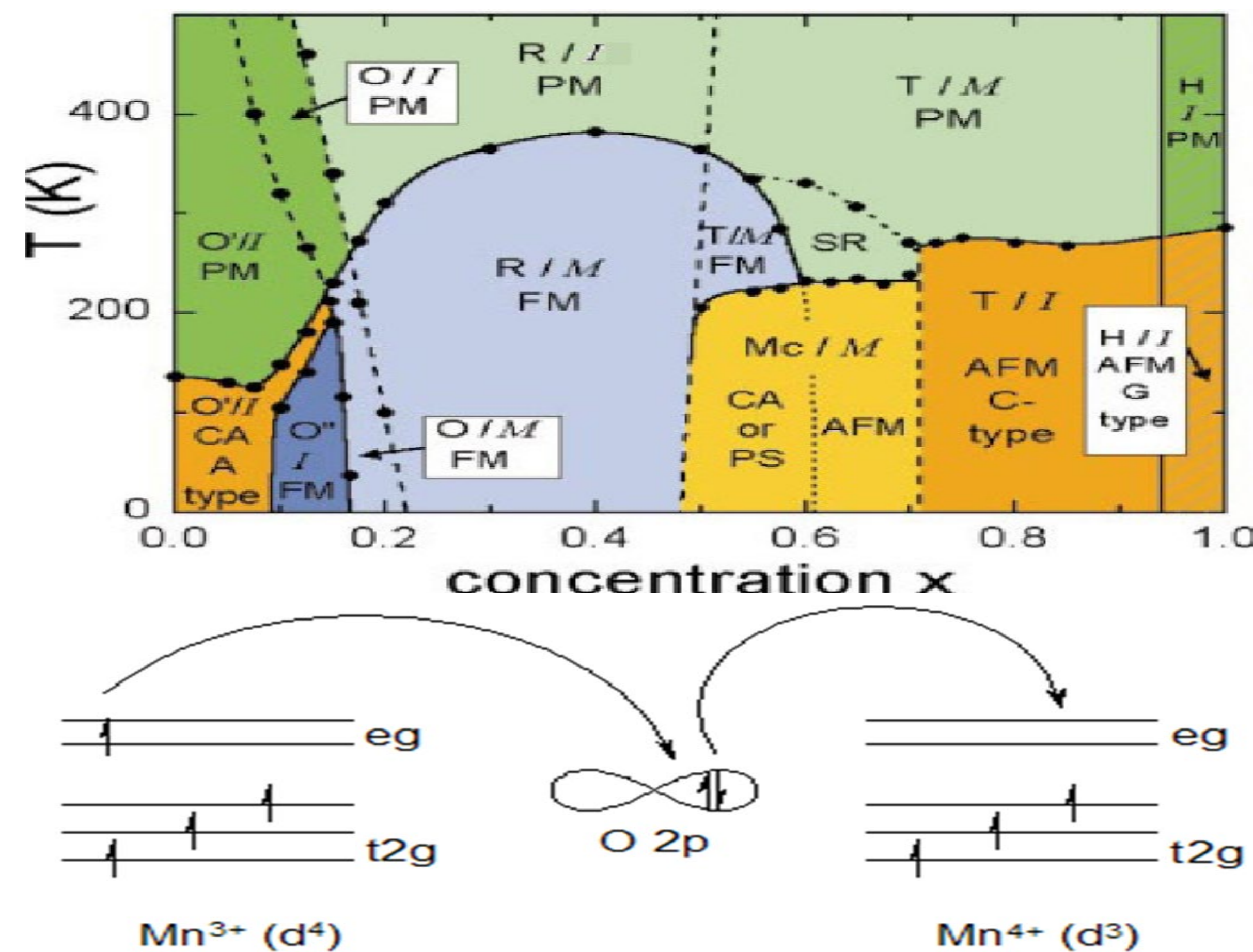
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Abstract

We have investigated the magnetic properties of thin films related to the standard CMR system $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$ where Y substituted for 50% of the La atoms. These $\text{La}_{1/3}\text{Y}_{1/3}\text{Sr}_{1/3}\text{MnO}_3$ films were grown as a random alloy where La, Y, and Sr atoms randomly occupied the A-site or as a superlattice where each unit-cell-thick layer stacked along the crystallographic (001) direction contained only one of the atoms La, Y, and Sr occupying the A-site. One of the key magnetic features of $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$ is a prominent ferromagnetic transition near 350 K. We find the substitution of La with Y suppresses this ferromagnetic transition in both the random alloy and the superlattice samples. In the superlattice sample we find a magnetic transition that is coincident with a metal-to-insulator transition we observe in electronic transport. In the random alloy sample, we see a similar magnetic transition but at lower temperatures where we find the sample is too insulating to measure electronic transport. We will compare our measurements on these $\text{La}_{1/3}\text{Y}_{1/3}\text{Sr}_{1/3}\text{MnO}_3$ samples with CMR thin films of $\text{La}_{2/3}\text{Sr}_{1/3}\text{MnO}_3$.

$\text{La}_{1-x}\text{Sr}_x\text{MnO}_3$ Bulk Phase Behavior



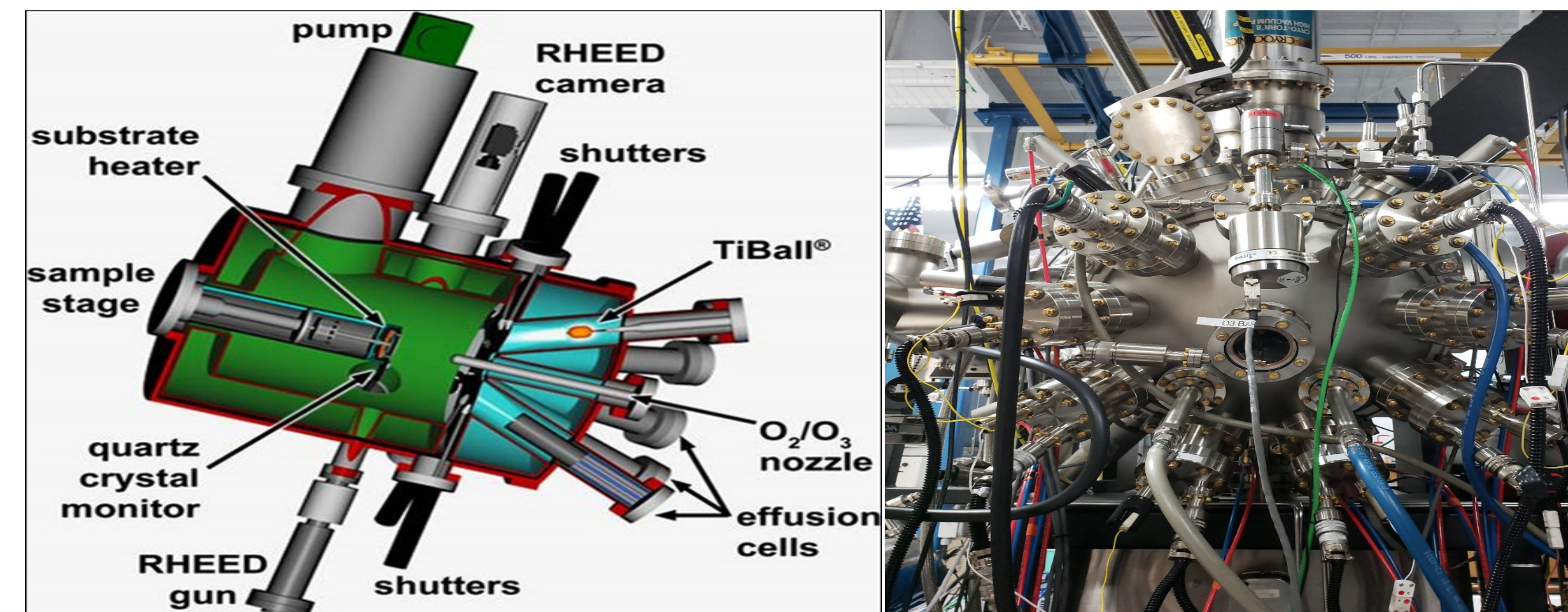
(Top) Bulk $\text{La}_{1-x}\text{Sr}_x\text{MnO}_3$ Phase diagram.

[Hemberger *et al*, PRB 66, 094410 (2002).]

(Bottom) Mechanism for double exchange interaction.

- $\text{La}_{1-x}\text{Sr}_x\text{MnO}_3$ has been extensively documented in bulk crystals with respect to temperature and strontium concentration.
- Undoped LaMnO_3 is a Mott insulator that is paramagnetic at high T and antiferromagnetic at low T .
- Around $x = 0.4$, $\text{La}_{1-x}\text{Sr}_x\text{MnO}_3$ is a paramagnetic insulator at higher temperatures but at lower temperatures it transitions to a ferromagnetic conductor.
- This ferromagnetic-conducting state is kinetically favorable around $x = 0.4$ at lower temperatures because the double exchange interaction allows for the delocalization of electrons across spin aligned manganese atoms, reducing free energy.

Molecular Beam Epitaxy



Side view diagram of an MBE chamber.

Front view picture of the chamber used in our growths.

- Samples grown using Molecular Beam Epitaxy (MBE).
- Carefully calibrated molecular beams of constituent elements produce thin films one atomic layer at a time.
- Constituent elements sources are heated in effusion cells to evaporate material into the chamber, forming collimated molecular beams.
- Ozone was introduced into the chamber to form oxides, allowing us to keep the chamber pressure low (5×10^{-7} Torr) due to ozone's high oxidizing potential.

XRD

